Express Mailing Label No.: EV 460255644 US

Docket No.: P0370US-7

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

NAKAMURA et al.

Examiner:

Unknown

Serial No.:

10/848,937

Art Unit: 2828

Filing Date:

May 18, 2004

For: METHOD FOR FABRICATING GROUP-III NITRIDE DEVICES AND DEVICES

FABRICATED USING METHOD

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR A CORRECTED FILING RECEIPT

Sir:

Transmitted herewith is a request for a corrected filing receipt. As noted on the enclosed filing receipt, the title is incorrectly listed as: METHOD FOR FABRICATING THIN FILM SEMICONDUCTOR DEVICES AND DEVICES FABRICATED USING Please correct the filing receipt to reflect the title to: METHOD FOR FABRICATING GROUP-III NITRIDE DEVICES AND DEVICES FABRICATED USING METHOD.

Respectfully submitted,

October 13, 2005

Jaye G. Heybl

Registration No.: 42,661 Attorney for Applicant

KOPPEL, JACOBS, PATRICK & HEYBL

555 St. Charles Drive, Suite 107 Thousand Oaks, California, 91360

Telephone: (805) 373-0060

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service via Express mail in an envelope addressed to: Commissioner of Patents, P.O. Box 1450,

Alexandria, Virginia 22313-1450

Mariana M. Rivas



United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE UNITED STATES DEFAMINENT OF COMMIT United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandris, Vigniss 22313-1450 www.usplo.gov

COTRABE

FILING OR 371 (c) DATE

ART UNIT

FIL FEE REC'D

ATTY.DOCKET NO

DRAWINGS TOT CLMS IND CLMS

8.937

05/18/2004

2828 1360 P0370US-7

Jave G. Hevbl KOPPEL, JACOBS, PATRICK & HEYBL Suite 107 555 St. Charles Drive Thousand Oaks, CA 91360

OC000000013268781*

KOPPEL JACOBS, PATRICKE

Date Mailed: 07/20/2004

48

CONFIRMATION NO. 5701

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE. NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Shuji Nakamura, Santa Barbara, CA; Steven DenBaars, Goleta, CA; John Edmond, Durham, NC; Chuck Swoboda, Durham, NC; Umesh Mishra, Santa Barbara, CA;

CALENDAR ENTRY

ACTION CALENDARED FO

Assignment For Published Patent Application

CREE, INC.;

Domestic Priority data as claimed by applicant

Foreign Applications

If Required, Foreign Filing License Granted: 07/19/2004

ACTION CALENDARED FOR

Projected Publication Date: To Be Determined - pending completion of Corrected Papers

Non-Publication Request: No

Early Publication Request: No

Title

-Method for fabricating thin film semiconductor devices and devices fabricated using method— METHOD FOR FABRICATING GROWP-III NITRIDE DEVICES Preliminary Class AND DEVICES FABRICATED USING METHOD

372

LICENSE FOR FOREIGN FILING UNDER
Title 35, United States Code, Section 184
Title 37, Code of Federal Regulations, 5.11 & 5.15

GRANTED

The applicant has been granted a license under 35 U.S.C. 184, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" followed by a date appears on this form. Such licenses are issued in all applications where the conditions for issuance of a license have been met, regardless of whether or not a license may be required as set forth in 37 CFR 5.15. The scope and limitations of this license are set forth in 37 CFR 5.15(a) unless an earlier license has been issued under 37 CFR 5.15(b). The license is subject to revocation upon written notification. The date indicated is the effective date of the license, unless an earlier license of similar scope has been granted under 37 CFR 5.13 or 5.14.

This license is to be retained by the licensee and may be used at any time on or after the effective date thereof unless it is revoked. This license is automatically transferred to any related applications(s) filed under 37 CFR 1.53(d). This license is not retroactive.

The grant of a license does not in any way lessen the responsibility of a licensee for the security of the subject matter as imposed by any Government contract or the provisions of existing laws relating to espionage and the national security or the export of technical data. Licensees should apprise themselves of current regulations especially with respect to certain countries, of other agencies, particularly the Office of Defense Trade Controls, Department of State (with respect to Arms, Munitions and Implements of War (22 CFR 121-128)); the Office of Export Administration, Department of Commerce (15 CFR 370.10 (j)); the Office of Foreign Assets Control, Department of Treasury (31 CFR Parts 500+) and the Department of Energy.

NOT GRANTED

No license under 35 U.S.C. 184 has been granted at this time, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" DOES NOT appear on this form. Applicant may still petition for a license under 37 CFR 5.12, if a license is desired before the expiration of 6 months from the filing date of the application. If 6 months has lapsed from the filing date of this application and the licensee has not received any indication of a secrecy order under 35 U.S.C. 181, the licensee may foreign file the application pursuant to 37 CFR 5.15(b).